

EMIF06-10006F2

IPAD™

MAIN PRODUCT CHARACTERISTICS

Where EMI filtering in ESD sensitive equipment is required:

- Mobile phones and communication systems
- Computers, printers and MCU Boards

DESCRIPTION

The EMIF06-10006F2 is a highly integrated devices designed to suppress EMI/RFI noise in all systems subjected to electromagnetic interferences. The EMIF06 flip-chip packaging means the package size is equal to the die size.

This filter includes an ESD protection circuitry which prevents the device from destruction when subjected to ESD surges up 15kV. This device includes 6 EMIF filters.

BENEFITS

- EMI symmetrical (I/O) low-pass filter
- High efficiency in EMI filtering
- Lead free package
- Very low PCB space consuming: 2.92mm x 1.29mm
- Very thin package: 0.65 mm
- High efficiency in ESD suppression (IEC61000-4-2 level 4)
- High reliability offered by monolithic integration
- High reducing of parasitic elements through integration and wafer level packaging

COMPLIES WITH THE FOLLOWING STANDARDS:

IEC 61000-4-2 level 4:

15kV (air discharge) 8kV (contact discharge)

MIL STD 883E - Method 3015-6 Class 3: 30kV

6 LINES EMI FILTER AND ESD PROTECTION

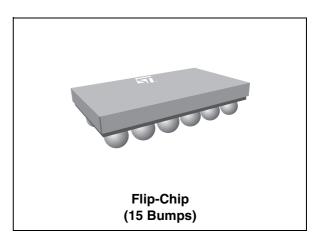
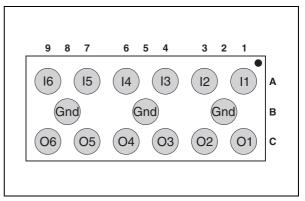


Table 1: Order Code

Part Number	Marking
EMIF06-10006F2	FT

Figure 1: Pin Configuration (ball side)



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November 2004

Figure 2: Basic Cell Configuration

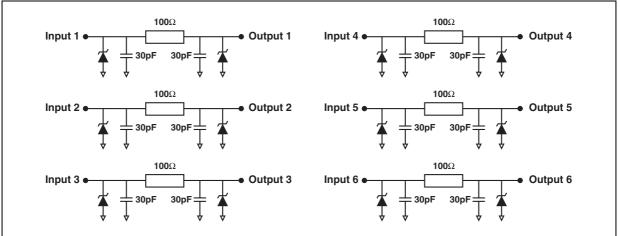
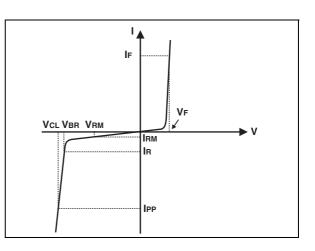


Table 2: Absolute Ratings (limiting values)

Symbol	Parameter and test conditions	Value	Unit
P _R	DC power per resistance	0.1	W
P _T	Total DC power per package	0.6	W
Тj	Maximum junction temperature	125	°C
T _{op}	Operating temperature range	- 40 to + 85	°C
T _{stg}	Storage temperature range	125	°C

Table 3: Electrical Characteristics (T_{amb} = 25 °C)

Symbol	Parameter	
V _{BR}	Breakdown voltage	
I _{RM}	Leakage current @ V _{RM}	
V _{RM}	Stand-off voltage	
V _{CL}	Clamping voltage	
R _d	Dynamic impedance	
I _{PP}	Peak pulse current	
R _{I/O}	Series resistance between Input and output	
C _{line}	Capacitance per line	



Symbol	Test conditions		Тур.	Max.	Unit
V _{BR}	I _R = 1 mA	5.5	7	9	V
I _{RM}	V _{RM} = 3.3 V per line			500	nA
R _{I/O}	I = 10 mA	80	100	120	Ω
C _{line}	$V_R = 2.5 V, F = 1 MHz, 30 mV$ (on filter cells)	50	60	70	pF

Figure 3: S21 (dB) attenuation measurements and Aplac simulation

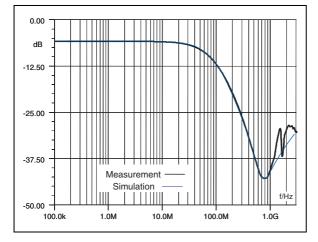


Figure 5: Digital crosstalk measurements

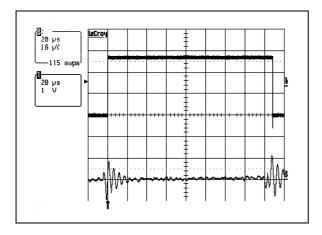
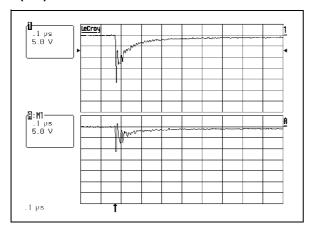


Figure 7: ESD response to IEC61000-4-2 (–15kV air discharge) on one imput V(in) and one output V(out)



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Figure 4: Analog crosstalk measurements

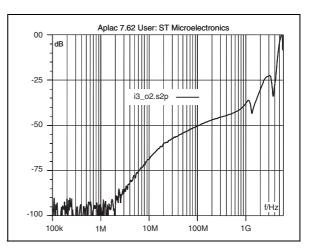


Figure 6: ESD response to IEC61000-4-2 (+15kV air discharge) on one imput V(in) and one output V(out)

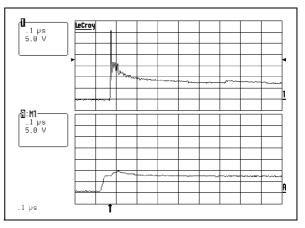
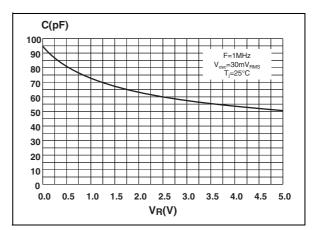


Figure 8: Line capacitance versus applied voltage for filter



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Figure 9: Aplac model

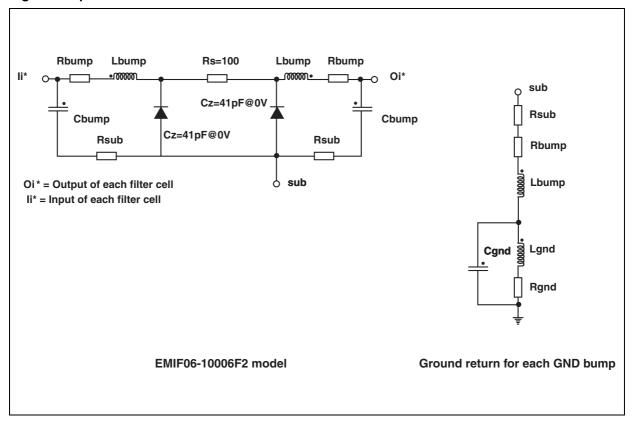
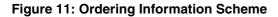


Figure 10: Aplac parameters

aplacvar RS	100Ω
aplacvar Cz	41 pF
aplacvar Lbump	50 pH
aplacvar Rbump	20 m
aplacvar Cbump	1.2 pF
aplacvar Rsub	100 m
aplacvar Rgnd	100 m
aplacvar Lgnd	100 pH
aplacvar Cgnd	0.15 pF



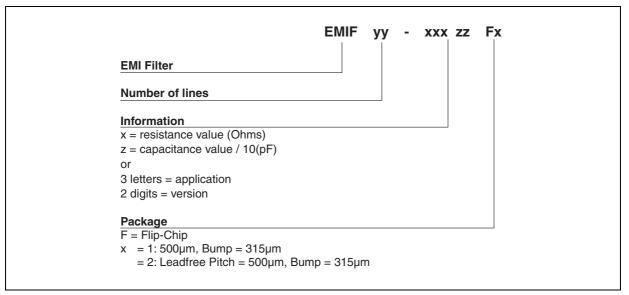
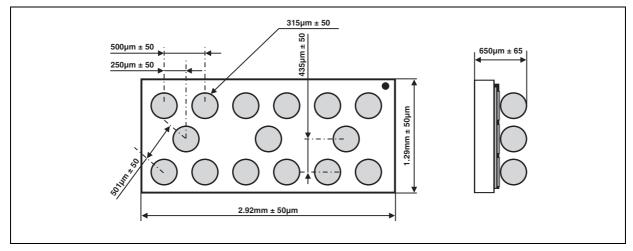


Figure 12: FLIP-CHIP Package Mechanical Data





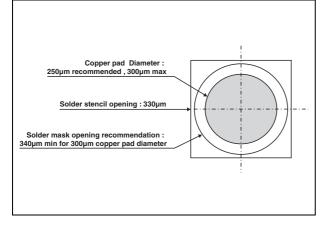
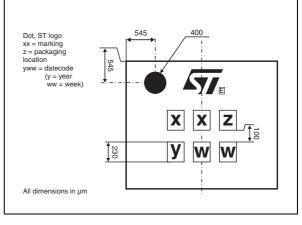


Figure 14: Marking



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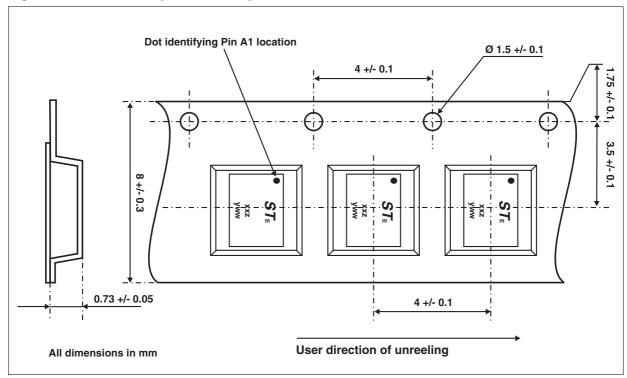


Figure 15: FLIP-CHIP Tape and Reel Specification

Table 4: Ordering Information

Ordering code	Marking	Package	Weight	Base qty	Delivery mode
EMIF06-10006F2	FS	Flip-Chip	5.4 mg	5000	Tape & reel 7"

Note: More packing informations are available in the application note AN1235: "Flip-Chip: Package description and recommendations for use" AN1751: "EMI Filters: Recommendations and measurements"

Table 5: Revision History

Date	Revision	Description of Changes
Sep-2004	1	First issue
19-Nov-2004	2	Figure 2 on page 2: Basic cell configuration corrected for I/O5 and I/O6.

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